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#### 100V N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>A</sub> = +25°C
100\/	15mΩ @ V <sub>GS</sub> = 10V	8.9A
100V	18mΩ @ V <sub>GS</sub> = 6.0V	7.9A

#### **Features and Benefits**

- 100% Unclamped Inductive Switch (UIS) Test in Production
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Description and Applications**

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize  $R_{DS(ON)}$ , yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

- Backlighting
- Power Management Functions
- DC-DC Converters

#### **Mechanical Data**

• Case: SO-8

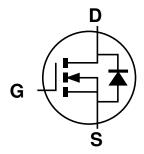
oxdot D

- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (Approximate)



Top View





Equivalent Circuit

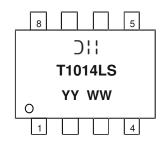
#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMT10H014LSS-13	SO-8	2,500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



T1014LS = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 16 = 2016)
WW = Week (01 to 53)



### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	100	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	8.9 7.1	А
Maximum Continuous Body Diode Forward Current (Note 6)			Is	3	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	54	Α
Avalanche Current, L = 3mH			I <sub>AS</sub>	7.5	Α
Avalanche Energy, L = 3mH			Eas	85	mJ

# Thermal Characteristics (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	$P_D$	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	100	°C/W
Total Power Dissipation (Note 6)	P <sub>D</sub>	1.67	W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	75	°C/W
Thermal Resistance, Junction to Case (Note 6)	Rejc	12	°C/W
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +150	°C

# Electrical Characteristics (T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	_	_	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.4	2	3	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
			11.5	15		$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	15	18	mΩ	$V_{GS} = 6V, I_D = 20A$	
		_	17.5	25		$V_{GS} = 4.5V, I_D = 5A$	
Diode Forward Voltage	$V_{SD}$	_	0.9	1.3	V	$V_{GS} = 0V, I_S = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	1871	_	pF	$V_{DS} = 50V$ , $V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	1	261	1			
Reverse Transfer Capacitance	C <sub>rss</sub>		7				
Gate Resistance	$R_{G}$	_	0.75	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg	_	33.3	_		V 50V L 40A	
Gate-Source Charge	Q <sub>gs</sub>	_	6.9	_	nC	$V_{DD} = 50V, I_D = 10A,$	
Gate-Drain Charge	$Q_{gd}$	_	5.1	_		$V_{GS} = 10V$	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.5	_			
Turn-On Rise Time	t <sub>R</sub>	_	7	_	ns	$\begin{split} V_{DD} &= 50 V, \ V_{GS} = 10 V, \\ I_D &= 10 A, \ R_G = 6 \Omega \end{split}$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	19.7	_	115		
Turn-Off Fall Time	t <sub>F</sub>	_	8.1	_			
Reverse Recovery Time	t <sub>RR</sub>	_	37.9	_	ns	1 400 11/14 4000/	
Reverse Recovery Charge	Q <sub>RR</sub>	_	51.9	_	nC	I <sub>F</sub> = 10A, di/dt = 100A/μs	

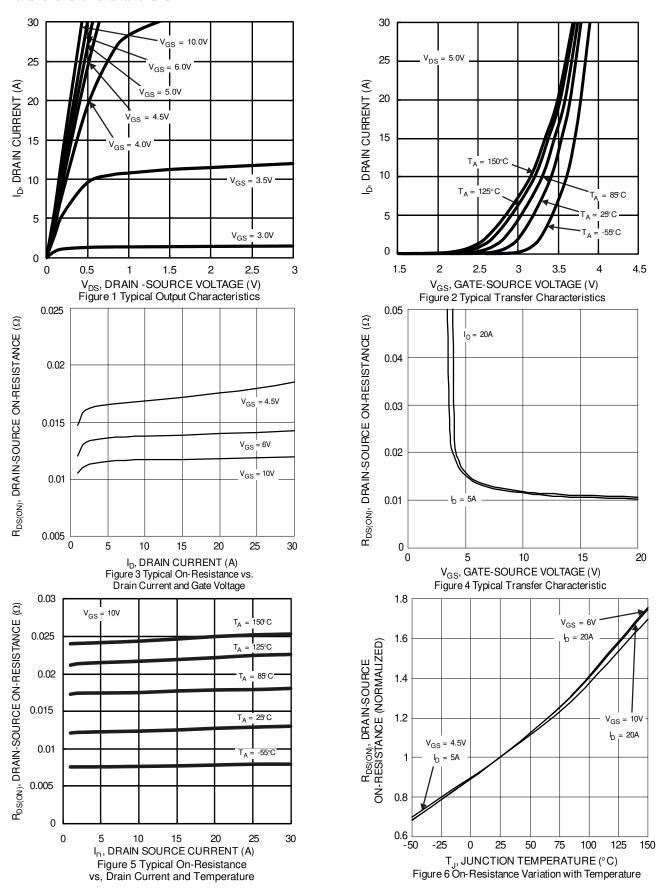
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

8. Guaranteed by design. Not subject to product testing.

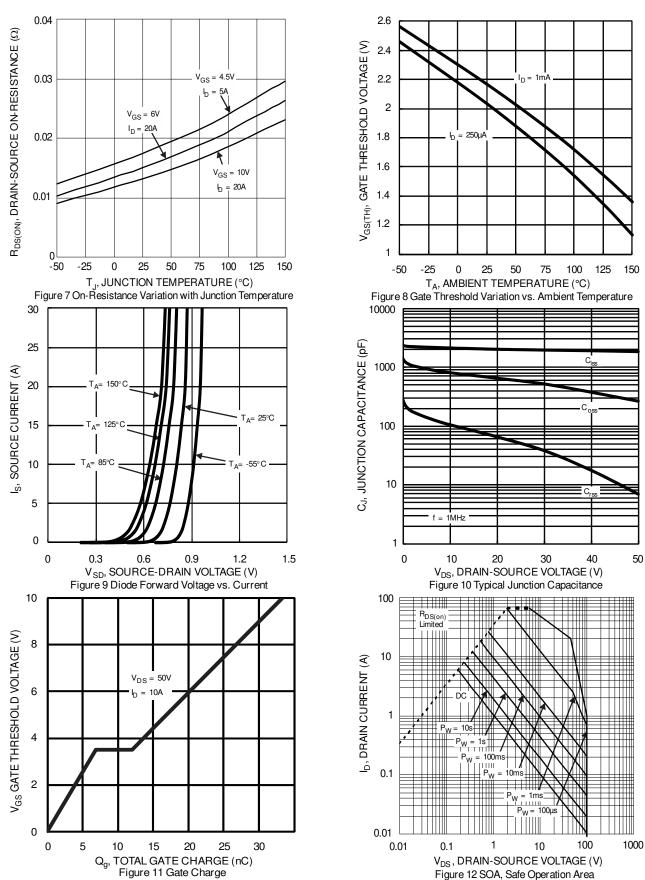
<sup>6.</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

<sup>7.</sup> Short duration pulse test used to minimize self-heating effect.

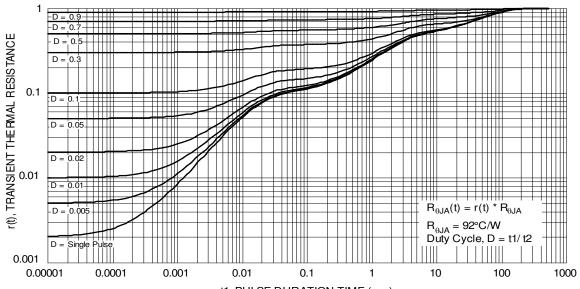












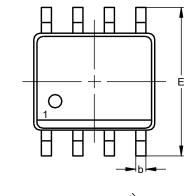
t1, PULSE DURATION TIME (sec) Figure 13 Transient Thermal Resistance

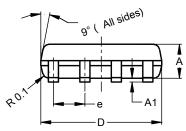


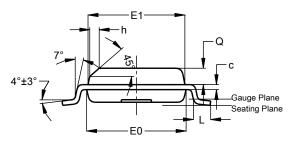
## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

**SO-8** 





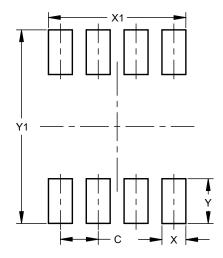


SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
q	0.30	0.50	0.40		
O	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е		-	1.27		
h	-	-	0.35		
Г	0.62	0.82	0.72		
Ø	0.60	0.70	0.65		
All Dimensions in mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Υ	1.505
Y1	6.50



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